

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):	Huajie Chen (et al.)	Examiner:	Laura Mary Menz
Serial No.:	10/597,066	Group Art Unit:	2813
Filed:	July 10, 2006	Attorney Docket No:	FIS920030342US1
Title:	METHOD OF FORMING THIN SGOI WAFERS WITH HIGH RELAXATION AND LOW STACKING FAULT DEFECT DENSITY		
Confirmation:	5456		

AMENDMENT AND RESPONSE

Mail Stop Non-Fee Amendment
Assistant Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This paper is submitted in response to an Office Action mailed June 12, 2008 in connection with the above-identified Application. A response to this June 12, 2008 Office Action is due by September 12, 2008. Therefore, this paper is being timely filed.

Amendments of the claims begin on page 2 of this paper.

Remarks begin on page 5 of this paper.